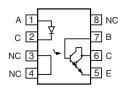


Vishay Semiconductors

Optocoupler, Photodarlington Output, Low Input Current, High Gain, with Base Connection





DESCRIPTION

The VO221AT, VO222AT, VO223AT are high current transfer ratio (CTR) optocouplers with a gallium arsenide infrared LED emitter and a silicon NPN photodarlington transistor detector.

The device has a CTR tested at 1 mA LED current. This low drive current permits easy interfacing from CMOS to LSTTL or TTL.

FEATURES

- Isolation test voltage, 4000 V_{RMS}
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- CUL file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-5 (VDE 0884) available with option 1

ORDER INFORMATION	
PART	REMARKS
VO221AT	CTR > 100 %, SOIC-8
VO222AT	CTR > 200 %, SOIC-8
VO223AT	CTR > 500 %, SOIC-8

ABSOLUTE MAXIMUM RA	TINGS			
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT			•	
Peak reverse voltage		V _R	6	V
Peak forward current	1 µs, 300 pps	I _{FM}	1	A
Forward continuous current		١ _F	60	mA
Power dissipation		P _{diss}	90	mW
Derate linearly from 25 °C			1.2	mW/°C
OUTPUT				
Collector emitter breakdown voltage		BV _{CEO}	30	V
Emitter collector breakdown voltage		BV _{ECO}	5	V
Collector base breakdown voltage		BV _{CBO}	70	V
I _{Cmax. DC}		I _{Cmax. DC}	50	mA
I _{Cmax.}	t < 1 ms	I _{Cmax.}	100	mA
Power dissipation		P _{diss}	150	mW
COUPLER			·	
Derate linearly from 25 °C			2	mW/°C
Isolation test voltage	t = 1 s	V _{ISO}	4000	V _{RMS}
Total package dissipation (at 25 °C ambient) (LED and detector)		P _{tot}	240	mW
Derate linearly from 25 °C			3.2	mW/°C
Storage temperature		T _{stg}	- 40 to + 150	°C
Operating temperature		T _{amb}	- 40 to + 100	°C

Note

 $T_{amb} = 25$ °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

T_{sld}

10

Soldering time at 260 °C

s

RoHS

COMPLIANT

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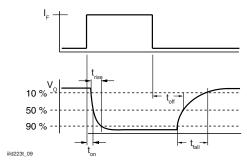
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT					1	I
Forward voltage	I _F = 1 mA	V _F		1	1.5	V
Reverse current	V _R = 6 V	I _R		0.1	100	μA
Capacitance	V _R = 0 V, f = 1 MHz	Co		25		pF
OUTPUT				•	•	
Collector emitter breakdown voltage	I _C = 100 μA	BV _{CEO}	30			V
Emitter collector breakdown voltage	I _C = 10 μA	BV _{ECO}	5			V
Collector base breakdown voltage	I _C = 10 μA	BV _{CBO}	70			V
Collector emitter leackage current	V _{CE} = 20 V	I _{CEO}			40	nA
Collector base current		I _{CBO}			1	nA
Emitter base current		I _{EBO}			1	nA
Collector emitter capacitance	V _{CE} = 10 V	C _{CE}		3.4		pF
Saturation voltage, collector emitter	I _{CE} = 0.5 mA	V _{CEsat}			1	V
COUPLER						
Capacitance (input to output)		C _{IO}		0.5		pF

Note

T_{amb} = 25 °C, unless otherwise specified. Minimum and maximum values are tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	I _F = 1 mA, V _{CE} = 5 V	VO221AT	CTR _{DC}	100			%
		VO222AT	CTR _{DC}	200			%
		VO223AT	CTR _{DC}	500			%

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time	V_{CC} = 10 V, R_L = 100 Ω , I_F = 5 mA	t _{on}		3		μs
Turn-off time	V_{CC} = 10 V, R_L = 100 Ω , I_F = 5 mA	t _{off}		3		μs



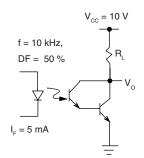


Fig. 1 - Switching Test Circuit



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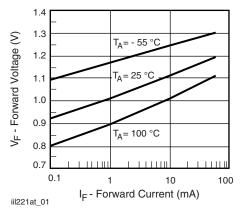
SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC 68 part 1)				40/100/21		
Polution degree				2		
Comparative tracking index		CTI	175		399	
Isolation test voltage	1 s	V _{ISO}	4000			V _{RMS}
Peak transient overvoltage		V _{IOTM}	6000			V
Peak insulation voltage		VIORM	560			V
Resistance (input to output)		R _{IO}		100		GΩ
Safety rating - power output		P _{SO}			350	mW
Safety rating - input current		I _{SI}			150	mA
Safety rating - temperature		T _{SI}			165	°C
External creepage distance			4			mm
External clearance distance			4			mm
Internal creepage distance			3.3			mm
Insulation thickness			0.2			mm

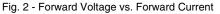
Note

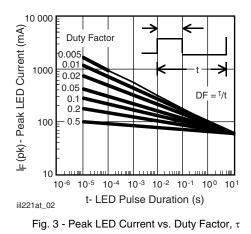
As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified







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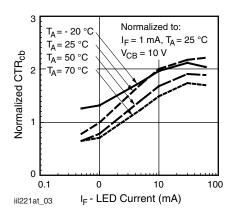


Fig. 4 - Normalized CTR_{cb} vs. I_F

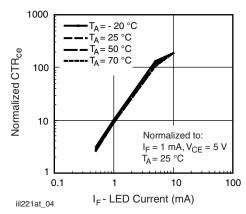
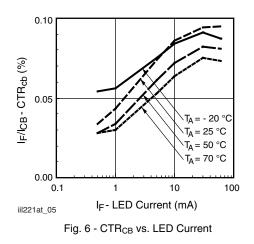


Fig. 5 - Normalized CTR_{CE} vs. LED Current



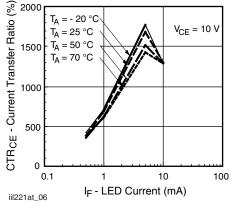
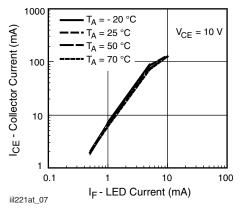
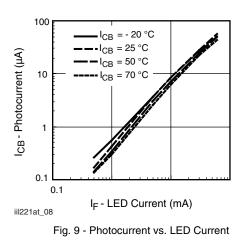


Fig. 7 - CTR vs. LED Current









Optocoupler, Photodarlington Output, Vishay Semiconductors Low Input Current, High Gain, with Base Connection

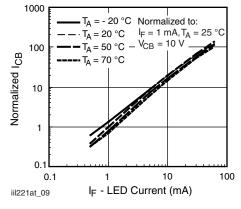
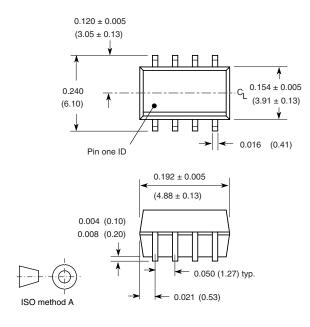
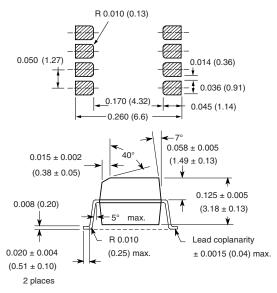


Fig. 10 - Normalized $I_{CB} \, vs. \, I_F$

PACKAGE DIMENSIONS in inches (millimeters)



i178003



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VISHAY.

Low Input Current, High Gain, with Base Connection

OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Vishay

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